

Product Preview

64K x 4 Bit Static RAM

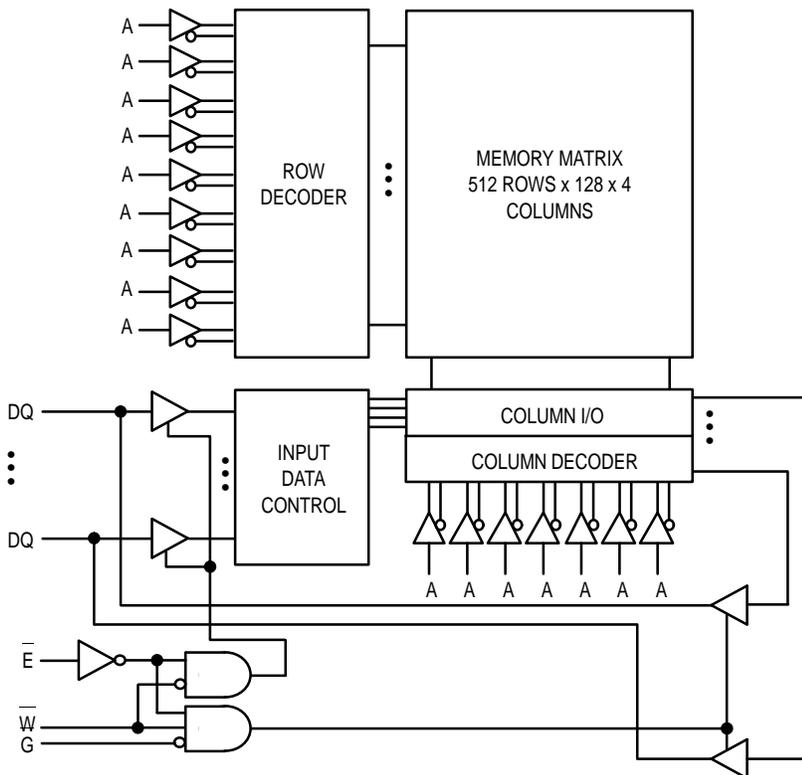
The MCM6709BR is a 262,144 bit static random access memory organized as 65,536 words of 4 bits. Static design eliminates the need for external clocks or timing strobes.

Output enable (\bar{G}) is a special control feature that provides increased system flexibility and eliminates bus contention problems.

The MCM6709BR meets JEDEC standards and is available in a revolutionary pinout 300 mil, 28 lead plastic surface-mount SOJ package.

- Single 5 V \pm 10% Power Supply
- Fully Static — No Clock or Timing Strobes Necessary
- All Inputs and Outputs are TTL Compatible
- Center Power and I/O Pins for Reduced Noise
- Three State Outputs
- Fast Access Times:
 - MCM6709BR-6 = 6 ns
 - MCM6709BR-7 = 7 ns
 - MCM6709BR-8 = 8 ns

BLOCK DIAGRAM



MCM6709BR



J PACKAGE
300 MIL SOJ
CASE 810B-03

PIN ASSIGNMENT

| | | | |
|-----------|----|----|-----------|
| A | 1 | 28 | A |
| A | 2 | 27 | A |
| A | 3 | 26 | A |
| A | 4 | 25 | A |
| \bar{E} | 5 | 24 | \bar{G} |
| DQ | 6 | 23 | DQ |
| VCC | 7 | 22 | VSS |
| VSS | 8 | 21 | VCC |
| DQ | 9 | 20 | DQ |
| \bar{W} | 10 | 19 | A |
| A | 11 | 18 | A |
| A | 12 | 17 | A |
| A | 13 | 16 | A |
| A | 14 | 15 | NC |

PIN NAMES

| | | |
|----------|-------|--------------------|
| <u>A</u> | | Address Inputs |
| <u>W</u> | | Write Enable |
| <u>G</u> | | Output Enable |
| <u>E</u> | | Chip Enable |
| DQ | | Data Input/Output |
| VCC | | + 5 V Power Supply |
| VSS | | Ground |
| NC | | No Connection |

All power supply and ground pins must be connected for proper operation of the device.

This document contains information on a new product under development. Motorola reserves the right to change or discontinue this product without notice.

TRUTH TABLE (X = Don't Care)

| E | G | W | Mode | Output | Cycle |
|---|---|---|--------------|------------------|-------------|
| H | X | X | Not Selected | High-Z | — |
| L | H | H | Read | High-Z | — |
| L | L | H | Read | D _{out} | Read Cycle |
| L | X | L | Write | D _{in} | Write Cycle |

ABSOLUTE MAXIMUM RATINGS (See Note)

| Rating | Symbol | Value | Unit |
|--|------------------------------------|--------------------------------|------|
| Power Supply Voltage | V _{CC} | - 0.5 to + 7.0 | V |
| Voltage Relative to V _{SS} for Any Pin Except V _{CC} | V _{in} , V _{out} | - 0.5 to V _{CC} + 0.5 | V |
| Output Current (per I/O) | I _{out} | ± 30 | mA |
| Power Dissipation | P _D | 2.0 | W |
| Temperature Under Bias | T _{bias} | - 10 to + 85 | °C |
| Operating Temperature | T _A | 0 to + 70 | °C |
| Storage Temperature — Plastic | T _{stg} | - 55 to + 125 | °C |

NOTE: Permanent device damage may occur if ABSOLUTE MAXIMUM RATINGS are exceeded. Functional operation should be restricted to RECOMMENDED OPERATING CONDITIONS. Exposure to higher than recommended voltages for extended periods of time could affect device reliability.

This device contains circuitry to protect the inputs against damage due to high static voltages or electric fields; however, it is advised that normal precautions be taken to avoid application of any voltage higher than maximum rated voltages to this high-impedance circuit.

This BiCMOS memory circuit has been designed to meet the dc and ac specifications shown in the tables, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow of at least 500 linear feet per minute is maintained.

DC OPERATING CONDITIONS AND CHARACTERISTICS

(V_{CC} = 5.0 V ± 10%, T_A = 0 to 70°C, Unless Otherwise Noted)

RECOMMENDED OPERATING CONDITIONS

| Parameter | Symbol | Min | Typ | Max | Unit |
|--|-----------------|---------|-----|------------------------|------|
| Supply Voltage (Operating Voltage Range) | V _{CC} | 4.5 | 5.0 | 5.5 | V |
| Input High Voltage | V _{IH} | 2.2 | — | V _{CC} + 0.3* | V |
| Input Low Voltage | V _{IL} | - 0.5** | — | 0.8 | V |

*V_{IH} (max) = V_{CC} + 0.3 V dc; V_{IH} (max) = V_{CC} + 2.0 V ac (pulse width ≤ 2.0 ns) or I ≤ 30.0 mA.

**V_{IL} (min) = - 0.5 V dc @ 30.0 mA; V_{IL} (min) = - 2.0 V ac (pulse width ≤ 2.0 ns) or I ≤ 30.0 mA.

DC CHARACTERISTICS

| Parameter | Symbol | Min | Max | Unit |
|---|---------------------|-----|-------|------|
| Input Leakage Current (All Inputs, V _{in} = 0 to V _{CC}) | I _{lkg(I)} | — | ± 1.0 | μA |
| Output Leakage Current (E = V _{IH} , V _{out} = 0 to V _{CC}) | I _{lkg(O)} | — | ± 1.0 | μA |
| Output High Voltage (I _{OH} = - 4.0 mA) | V _{OH} | 2.4 | — | V |
| Output Low Voltage (I _{OL} = 8.0 mA) | V _{OL} | — | 0.4 | V |

POWER SUPPLY CURRENTS

| Parameter | Symbol | MCM6709BR-6 | MCM6709BR-7 | MCM6709BR-8 | Unit | Notes |
|--|------------------|-------------|-------------|-------------|------|---------|
| AC Active Supply Current (I _{out} = 0 mA, V _{CC} = max, f = f _{max}) | I _{CCA} | 215 | 205 | 195 | mA | 1, 2, 3 |
| AC Standby Current (E = V _{IH} , V _{CC} = max, f = f _{max}) | I _{SB1} | 95 | 85 | 75 | mA | 1, 2, 3 |
| CMOS Standby Current (V _{CC} = max, f = 0 MHz, E ≥ V _{CC} - 0.2 V, V _{in} ≤ V _{SS} , or ≥ V _{CC} - 0.2 V) | I _{SB2} | 20 | 20 | 20 | mA | |

NOTES:

- Reference AC Operating Conditions and Characteristics for input and timing (V_{IH}/V_{IL}, t_r/t_f, pulse level 0 to 3.0 V, V_{IH} = 3.0 V).
- All addresses transition simultaneously low (LSB) and then high (MSB).
- Data states are all zero.

CAPACITANCE (f = 1.0 MHz, dV = 3.0 V, T_A = 25°C, Periodically Sampled Rather Than 100% Tested)

| Parameter | Symbol | Max | Unit |
|--|------------------|-----|------|
| Address Input Capacitance | C _{in} | 5 | pF |
| Control Pin Input Capacitance(E, G, W) | C _{in} | 6 | pF |
| Input/Output Capacitance | C _{I/O} | 6 | pF |

AC OPERATING CONDITIONS AND CHARACTERISTICS

(V_{CC} = 5.0 V ± 10%, T_A = 0 to + 70°C, Unless Otherwise Noted)

Input Timing Measurement Reference Level 1.5 V Output Timing Measurement Reference Level 1.5 V
 Input Pulse Levels 0 to 3.0 V Output Load See Figure 1a
 Input Rise/Fall Time 2 ns

READ CYCLES 1 AND 2 (See Notes 1 and 2)

| Parameter | Symbol | MCM6709BR-6 | | MCM6709BR-7 | | MCM6709BR-8 | | Unit | Notes |
|-------------------------------------|-------------------|-------------|-----|-------------|-----|-------------|-----|------|---------|
| | | Min | Max | Min | Max | Min | Max | | |
| Read Cycle Time | t _{AVAV} | 6 | — | 7 | — | 8 | — | ns | 3 |
| Address Access Time | t _{AVQV} | — | 6 | — | 7 | — | 8 | ns | |
| Chip Enable Access Time | t _{ELQV} | — | 6 | — | 7 | — | 8 | ns | |
| Output Enable Access Time | t _{GLQV} | — | 4 | — | 4 | — | 4 | ns | |
| Output Hold from Address Change | t _{AXQX} | 3 | — | 3 | — | 3 | — | ns | |
| Chip Enable Low to Output Active | t _{ELQX} | 3 | — | 3 | — | 3 | — | ns | 4, 5, 6 |
| Output Enable Low to Output Active | t _{GLQX} | 0 | — | 0 | — | 0 | — | ns | 4, 5, 6 |
| Chip Enable High to Output High-Z | t _{EHQZ} | — | 3 | — | 3.5 | — | 3.5 | ns | 4, 5, 6 |
| Output Enable High to Output High-Z | t _{GHQZ} | — | 3 | — | 3.5 | — | 3.5 | ns | 4, 5, 6 |

NOTES:

1. W is high for read cycle.
2. Product sensitivities to noise require proper grounding and decoupling of power supplies as well as minimization or elimination of bus contention conditions during read and write cycles.
3. All read cycle timings are referenced from the last valid address to the first transitioning address.
4. At any given voltage and temperature, t_{EHQZ} max is less than t_{ELQX} min, and t_{GHQZ} max is less than t_{GLQX} min, both for a given device and from device to device.
5. Transition is measured 200 mV from steady-state voltage with load of Figure 1b.
6. This parameter is sampled and not 100% tested.

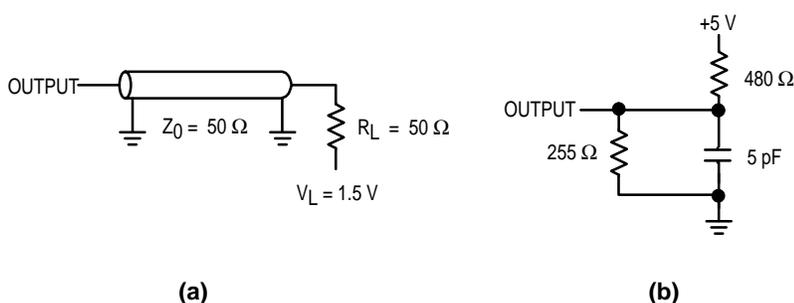
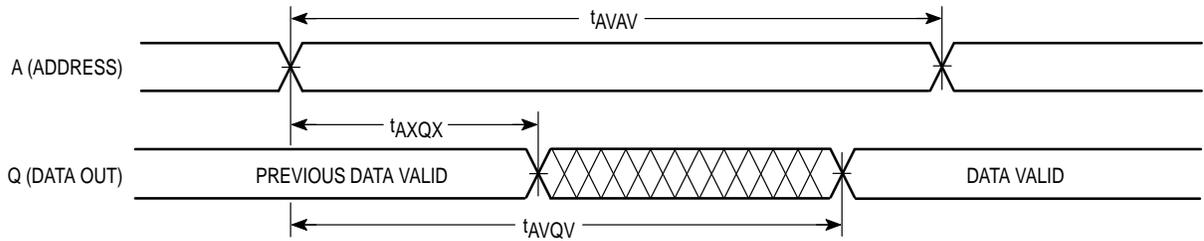


Figure 1. AC Test Loads

TIMING LIMITS

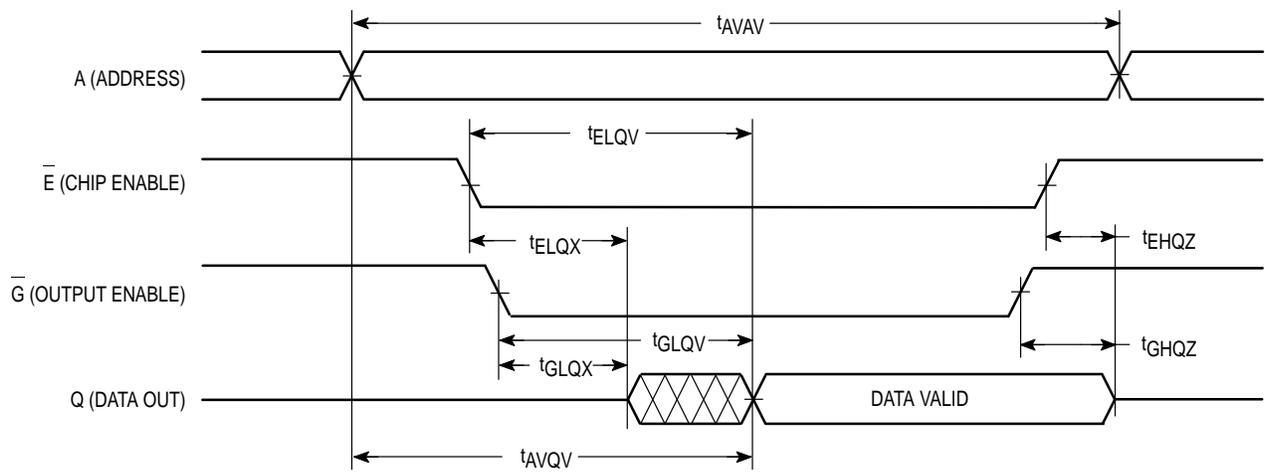
The table of timing values shows either a minimum or a maximum limit for each parameter. Input requirements are specified from the external system point of view. Thus, address setup time is shown as a minimum since the system must supply at least that much time. On the other hand, responses from the memory are specified from the device point of view. Thus, the access time is shown as a maximum since the device never provides data later than that time.

READ CYCLE 1 (See Note)



NOTE: Device is continuously selected ($\bar{E} = V_{IL}$, $\bar{G} = V_{IL}$).

READ CYCLE 2 (See Note)



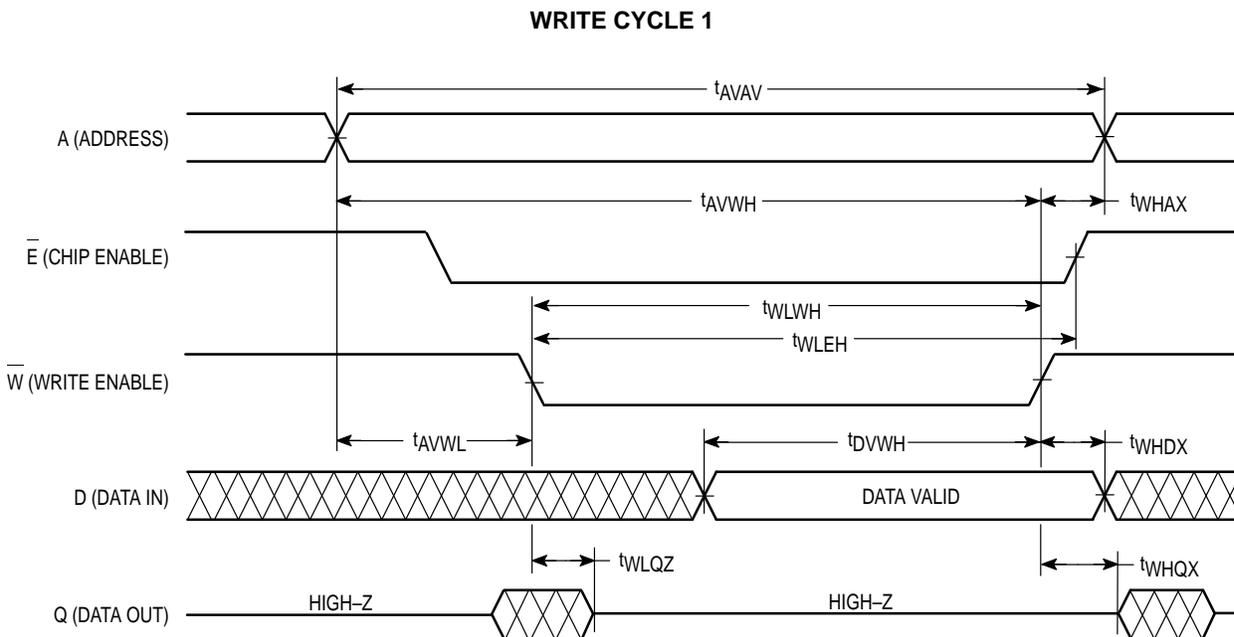
NOTE: Addresses valid prior to or coincident with \bar{E} going low.

WRITE CYCLE 1 (\bar{W} Controlled, See Notes 1 and 2)

| Parameter | Symbol | MCM6709BR-6 | | MCM6709BR-7 | | MCM6709BR-8 | | Unit | Notes |
|-------------------------------|--------------------------|-------------|-----|-------------|-----|-------------|-----|------|---------|
| | | Min | Max | Min | Max | Min | Max | | |
| Write Cycle Time | t_{AVAV} | 6 | — | 7 | — | 8 | — | ns | 3 |
| Address Setup Time | t_{AVWL} | 0 | — | 0 | — | 0 | — | ns | |
| Address Valid to End of Write | t_{AVWH} | 6 | — | 7 | — | 8 | — | ns | |
| Write Pulse Width | t_{WLWH} t_{WLEH} | 6 | — | 7 | — | 8 | — | ns | |
| Data Valid to End of Write | t_{DVWH} | 3 | — | 3.5 | — | 3.5 | — | ns | |
| Data Hold Time | t_{WHDX} | 0 | — | 0 | — | 0 | — | ns | |
| Write Low to Data High-Z | t_{WLQZ} | — | 3.5 | — | 3.5 | — | 3.5 | ns | 4, 5, 6 |
| Write High to Output Active | t_{WHQX} | 3 | — | 3 | — | 3 | — | ns | 4, 5, 6 |
| Write Recovery Time | t_{WHAX} | 0 | — | 0 | — | 0 | — | ns | |

NOTES:

1. A write occurs during the overlap of \bar{E} low and \bar{W} low.
2. Product sensitivities to noise require proper grounding and decoupling of power supplies as well as minimization or elimination of bus contention conditions during read and write cycles.
3. All write cycle timing is referenced from the last valid address to the first transitioning address.
4. Transition is measured 200 mV from steady state voltage with load of Figure 1b.
5. This parameter is sampled and not 100% tested.
6. At any given voltage and temperature, t_{WLQZ} max is less than t_{WHQX} min both for a given device and from device to device.



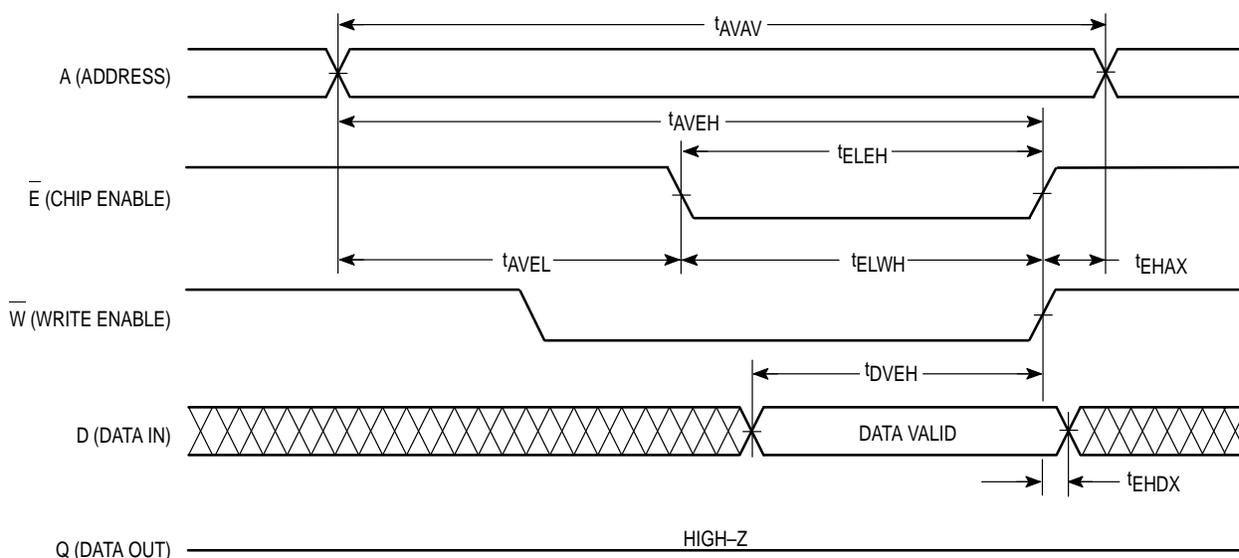
WRITE CYCLE 2 (\bar{E} Controlled, See Notes 1 and 2)

| Parameter | Symbol | MCM6709BR-6 | | MCM6709BR-7 | | MCM6709BR-8 | | Unit | Notes |
|-------------------------------|----------------------------|-------------|-----|-------------|-----|-------------|-----|------|-------|
| | | Min | Max | Min | Max | Min | Max | | |
| Write Cycle Time | t_{AVAV} | 6 | — | 7 | — | 8 | — | ns | 3 |
| Address Setup Time | t_{AVEL} | 0 | — | 0 | — | 0 | — | ns | |
| Address Valid to End of Write | t_{AVEH} | 6 | — | 7 | — | 8 | — | ns | |
| Chip Enable to End of Write | t_{ELEH} , t_{ELWH} | 5 | — | 6 | — | 7 | — | ns | 4, 5 |
| Data Valid to End of Write | t_{DVEH} | 3 | — | 3.5 | — | 3.5 | — | ns | |
| Data Hold Time | t_{EHDX} | 0 | — | 0 | — | 0 | — | ns | |
| Write Recovery Time | t_{EHAX} | 0 | — | 0 | — | 0 | — | ns | |

NOTES:

1. A write occurs during the overlap of \bar{E} low and \bar{W} low.
2. Product sensitivities to noise require proper grounding and decoupling of power supplies as well as minimization or elimination of bus contention conditions during read and write cycles.
3. All write cycle timing is referenced from the last valid address to the first transitioning address.
4. If \bar{E} goes low coincident with or after \bar{W} goes low, the output will remain in a high impedance condition.
5. If \bar{E} goes high coincident with or before \bar{W} goes high, the output will remain in a high impedance condition.

WRITE CYCLE 2

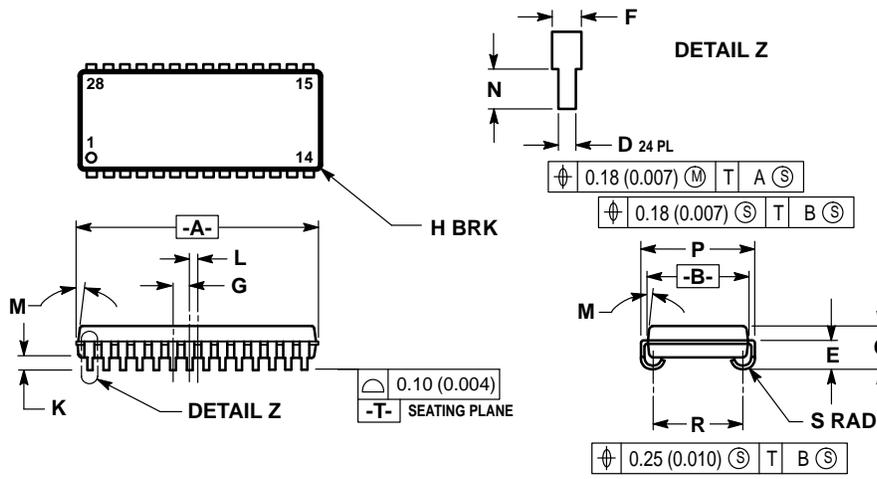


ORDERING INFORMATION
(Order by Full Part Number)

MCM 6709BR X X X
 Motorola Memory Prefix _____
 Part Number _____
 Shipping Method (R = Tape and Reel, Blank = Rails)
 Speed (6 = 6 ns, 7 = 7 ns, 8 = 8 ns)
 Package (J = 300 mil SOJ)

Full Part Numbers — MCM6709BRJ6 MCM6709BRJ6R
 MCM6709BRJ7 MCM6709BRJ7R
 MCM6709BRJ8 MCM6709BRJ8R

**28 LEAD
300 MIL SOJ
CASE 810B-03**



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. DIMENSION A & B DO NOT INCLUDE MOLD PROTRUSION. MOLD PROTRUSION SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
3. CONTROLLING DIMENSION: INCH.
4. DIM R TO BE DETERMINED AT DATUM -T-.
5. 810B-01 AND -02 OBSOLETE, NEW STANDARD 810B-03.

| DIM | MILLIMETERS | | INCHES | |
|-----|-------------|-------|-----------|-------|
| | MIN | MAX | MIN | MAX |
| A | 18.29 | 18.54 | 0.720 | 0.730 |
| B | 7.50 | 7.74 | 0.295 | 0.305 |
| C | 3.26 | 3.75 | 0.128 | 0.148 |
| D | 0.39 | 0.50 | 0.015 | 0.020 |
| E | 2.24 | 2.48 | 0.088 | 0.098 |
| F | 0.67 | 0.81 | 0.026 | 0.032 |
| G | 1.27 BSC | | 0.050 BSC | |
| H | — | 0.50 | — | 0.020 |
| K | 0.89 | 1.14 | 0.035 | 0.045 |
| L | 0.64 BSC | | 0.025 BSC | |
| M | 0° | 10° | 0° | 10° |
| N | 0.76 | 1.14 | 0.030 | 0.045 |
| P | 8.38 | 8.64 | 0.330 | 0.340 |
| R | 6.60 | 6.86 | 0.260 | 0.270 |
| S | 0.77 | 1.01 | 0.030 | 0.040 |

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